

# DMR935E2

Silicon PNP epitaxial planar type (Tr)  
Silicon epitaxial planar type (CCD load device)

For CCD output circuits

■ Features

- High transition frequency  $f_T$
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

■ Packaging

DMR935E20R Embossed type (Thermo-compression sealing): 8000 pcs / reel (standard)

■ Absolute Maximum Ratings  $T_a = 25^\circ\text{C}$

Parameter		Symbol	Rating	Unit
Tr1	Collector-base voltage (Emitter open)	$V_{CBO}$	-24	V
	Collector-emitter voltage (Base open)	$V_{CEO}$	-20	V
	Emitter-base voltage (Collector open)	$V_{EBO}$	-3	V
	Collector current	$I_C$	-50	mA
CCD load device	Limiting element voltage	$V_{max}$	40	V
	Limiting element current	$I_{max}$	10	mA
Overall	Total power dissipation *	$P_T$	125	mW
	Junction temperature	$T_j$	150	$^\circ\text{C}$
	Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

Note) \*: Measuring on substrate at 17 mm × 10 mm × 1 mm

■ Electrical Characteristics  $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

• Tr1

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	$I_C = -100 \mu\text{A}, I_E = 0$	-24			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_E = -10 \mu\text{A}, I_C = 0$	-3			V
Base-emitter voltage	$V_{BE}$	$V_{CE} = -10 \text{V}, I_C = -2 \text{mA}$		720		mV
Forward current transfer ratio	$h_{FE}$	$V_{CE} = -10 \text{V}, I_C = -2 \text{mA}$	100		250	—
Transition frequency	$f_T$	$V_{CE} = -10 \text{V}, I_C = -2 \text{mA}$		1400		MHz

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Pulse measurement

• CCD load device

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Pinchi off current	$I_P$	$V_{DS} = 8 \text{V}, V_G = 0$	5.0		7.0	mA
Output impedance	$Z_O$	$V_{DS} = 8 \text{V}, V_G = 0$		0.02		$\mu\Omega$

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

■ Package

• Code

SSMini6-F3-B

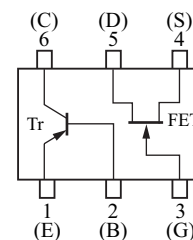
Package dimension clicks here.→

• Pin Name

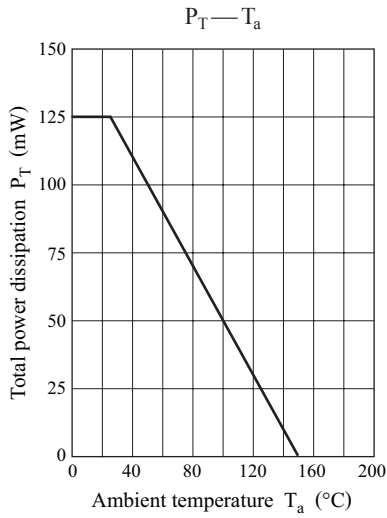
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|------------|--------------|
| 1: Emitter | 4: Source    |
| 2: Base    | 5: Drain     |
| 3: Gate    | 6: Collector |

■ Marking Symbol: X5

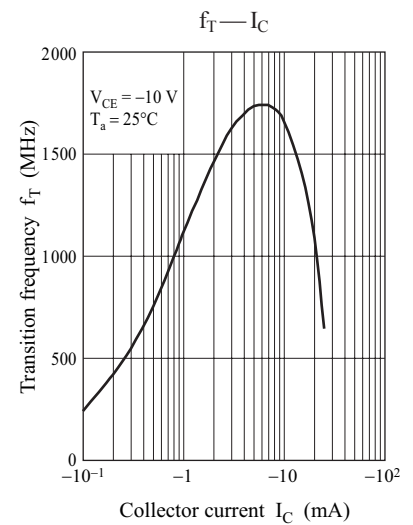
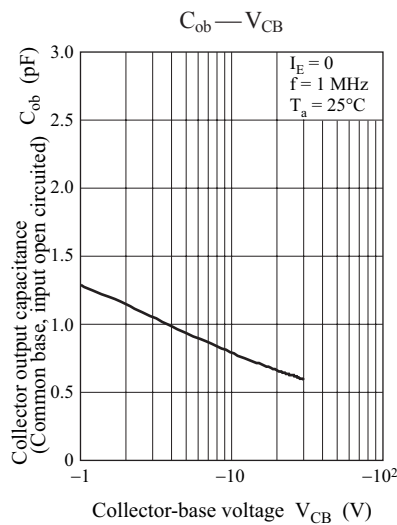
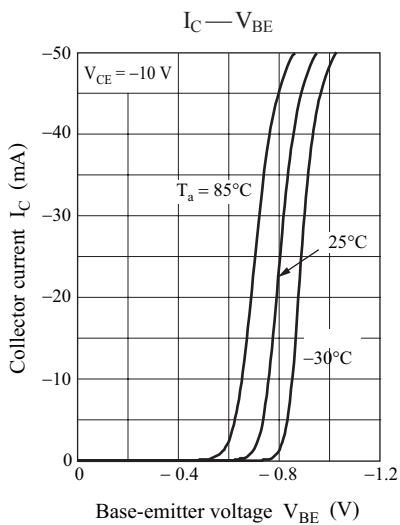
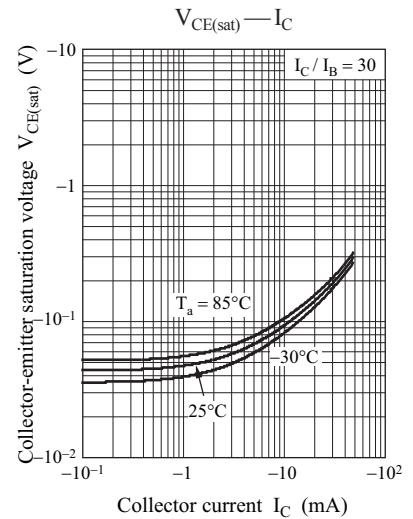
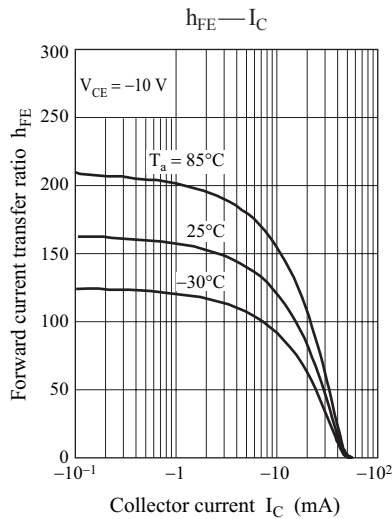
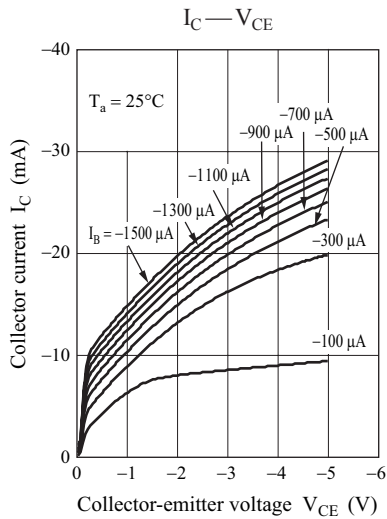
■ Internal Connection



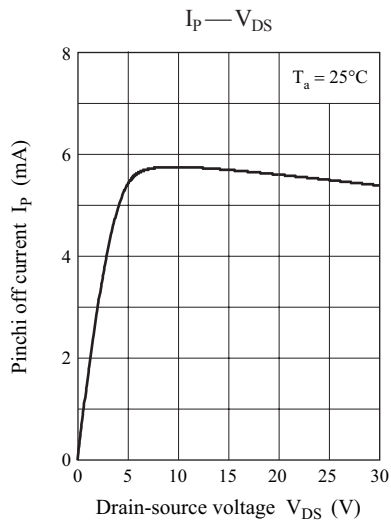
Common characteristics chart



Characteristics charts of Tr



Characteristics charts of CCD



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